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Correlation-induced self-doping in intercalated iron-pnictide superconductor Ba₂Ti₂Fe₂As₄O

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The electronic structure of the intercalated iron-based superconductor $Ba_2Ti_2Fe_2As_4O$ ($T_c \sim 21.5$ K) has been investigated by using angle-resolved photoemission spectroscopy and combined local density approximation and dynamical mean field theory calculations. The electronic states near the Fermi level are dominated by both the Fe 3*d* and Ti 3*d* orbitals, indicating that the spacing layers separating different FeAs layers are also metallic. By counting the enclosed volumes of the Fermi surface sheets, we observe a large self-doping effect, *i.e.* 0.25 electrons per unit cell are transferred from the FeAs layer to the Ti₂As₂O layer, leaving the FeAs layer in a hole-doped state. This exotic behavior is successfully reproduced by our dynamical mean field calculations, in which the self-doping effect is attributed to the electronic correlations in the Fe 3*d* shell. Our work provides an alternative route of effective doping without element substitution for iron-based superconductors.

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In iron-based superconductors (IBSCs), the most common ways to suppress long-range antiferromagnetic order and obtain high- T_c superconductivity is to introduce carriers [1–3] and/or internal strain [4-6] by element substitution. However, an inevitable problem is that element substitution also introduces disorder, and impurity scattering is believed to be detrimental to superconductivity [7], though not as seriously as in cuprate superconductors. It has been revealed that the impurity scattering effects are site dependent and the scattering strength is gradually reduced when the dopants move away from the Fe plane [8, 9]. This may partially explain why the maximum T_c is much higher and the superconducting dome is much wider in (Ba,K)Fe₂As₂ as compared with $Ba(Fe,Co)_2As_2$ [8]. Therefore, finding an alternative way to dope carriers but without introducing disorder would be a promising path for reaching higher T_c superconductivity.

A remarkable feature in the IBSCs is that there is an intimate relationship between the electronic correlations and the *d*-shell occupancy. For hole doping, extremely low coherence temperatures are expected, while electron doping reinforces Fermi-liquid properties [10, 11]. Moreover, the orbital polarization can be tuned by the magnitudes of the Coulomb interaction *U* and the Hund's rule coupling *J*, leading to a redistribution of electrons among five Fe 3*d* orbitals [12]. Electronic correlations weaken the hybridization between Fe and ligand atoms, reducing the effective occupancy of the Fe 3*d* orbitals [13]. However, as the total electron count on the Fe and ligand atoms in crystals, such as BaFe₂As₂, is conserved, such charge redistribution between them does not produce any doping effect on the Fermi surfaces (FSs).

In this work, we prove that doping can be induced by electronic correlations in the IBSC Ba₂Ti₂Fe₂As₄O (Ba22241, T_c ~ 21.5 K) due to the intercalation of metallic Ti₂As₂O layers. Ba22241 can be regarded as a superlattice consisting of alternating stacking of BaFe₂As₂ and BaTi₂As₂O layers [Fig. 1(a)] [14]. Compared with other IBSCs, the most distinctive characteristic of Ba22241 is the metallic nature of the intercalated layers, which contributes distinctly to the density of states (DOS) at the Fermi level (E_F) [15]. Our ARPES measurements suggest that the low-energy band dispersions can be regarded as a superposition of the band structures of the FeAs and Ti₂As₂O layers. By counting the volumes of the FSs, we find that about 0.25 electrons per unit cell are transferred from the FeAs layer to the Ti₂As₂O layer. This exotic behavior is successfully reproduced by dynamical mean field-based electronic structure calculations, which allow us to identify electronic Coulomb correlations in the 3d shells as the main cause for this self-doping effect.

High-quality single crystals of Ba22241 were synthesized by the flux method [16]. ARPES measurements were performed at beamlines PGM and APPLE-PGM of the Synchrotron Radiation Center (Wisconsin) with Scienta R4000 and SES 200 analyzers, respectively, as well as at beamline SIS of the Swiss Light Source (PSI) with Scienta R4000. The energy and angular resolutions were set at 15-30 meV and 0.2° , respectively. The samples were cleaved *in situ* and measured in the temperature range between 25 and 150 K in a vacuum better than 3×10^{-11} Torr. The ARPES data were taken with vertical exit slits under horizontal (HP) or vertical (VP) polarized lights at SRC and with horizontal exit slit at

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FIG. 1. (Color online) (a) Crystal structures of $BaFe_2As_2$, $BaTi_2As_2O$ and $Ba_2Ti_2Fe_2As_4O$. (b) Schematic Brillouin zones for one and two Fe (Ti) per unit cell. Red lines indicate the measurement locations in panel (c). (c) Two-dimensional (2D) curvature intensity plot [17] of the ARPES data along MZX Γ M recorded at 150 K and photon energy hv = 55 eV with HP. The LDA bands are also plotted without renormalization for comparison. (d) Momentum-resolved spectral function calculated within LDA + DMFT at T = 145 K. Red curves represent the extracted experimental band dispersions.

Figure 1(c) shows the experimental band dispersions along the high-symmetry lines MZXITM in an energy range within 2.2 eV below E_F . The band dispersions are much more complex than those of other IBSCs due to the contribution of the metallic Ti₂As₂O layers. To understand the multiband electronic structure, we superimpose the Kohn-Sham band structure of density functional theory within the local density approximation (LDA) as calculated within Wien2k [18] on top of the experimental data in Fig. 1(c). We use the experimental crystal structure of Ref. [14] as input. The experimental band dispersions below -1 eV match well the LDA bands, which are mainly derived from As 4p of the Ti₂As₂O layers [Fig. S3 in the Supplement Materials]. Obvious discrepancies between the experimental results and the LDA calculations are observed within 1 eV below E_F , where the DOS is mainly of Fe 3d and Ti 3d characters. The deviation can be qualitatively attributed to non-negligible correlation effects between the 3d electrons, for which the self-energy leads to strong band renormalizations near E_F , as observed in other IBSCs [19]. To analyze the effects of Coulomb correlations on the electronic structure, we have performed LDA + dynamical mean field theory (DMFT) calculations of the momentum-resolved spectral function, starting from the above Kohn-Sham band structure and the implementation of Ref. [20] using projected atomic orbitals. Since our target compound contains two different atomic species with partially filled narrow d-shells, we have generalized the usual LDA + DMFT scheme to include effective local Coulomb interactions on both the Fe-3d and Ti-3*d* shells. We use U = 2.64 eV [3.50 eV] and J = 0.96 eV[0.74 eV] for the Hubbard interactions (monopole Slater integral F₀ and Hund's coupling on Fe [Ti]), and a multi-orbital 2

around mean field double counting based on the LDA electron count [21]. The resulting 10-orbital many-body problem was solved within a continuous-time Quantum Monte Carlo scheme, as implemented in the TRIQS toolbox [22]. The corresponding results are presented in Fig. 1(d), which reproduce well the experimental band dispersions. The Fe 3*d* derived bands are strongly renormalized compared with the LDA results and their spectral intensities are very diffuse due to a large quasiparticle broadening encoded in the imaginary part of the DMFT self energy.



FIG. 2. (Color online) (a-e) 2D curvature intensity plots of the near- E_F ARPES data recorded at hv = 55 eV. The momentum locations are indicated as red vertical lines in panel (f). To illustrate the Fe-3d related band dispersions more clearly, the data taken at 30 K are shown in panels (a), (b) and (d). As the Ti-3d related band dispersions are dramatically changed across the transition at 125 K [Fig. S2 in the Supplement Materials], the data taken at 150 K are shown in panels (c) and (e).

A prominent feature in the calculations is that the intercalated Ti₂As₂O layers contribute significantly to the DOS at E_F , demonstrating the metallic nature of the intercalated layers in this system. To clarify the effects on the low-energy electronic states of the FeAs layers, we show the band dispersions near E_F in Fig. 2. All the cuts are parallel to the ΓM direction, as schematically plotted in Fig. 2(f). We identify three hole-like bands near Γ [Figs. 2(a) and 2(b)], one holelike band near X [Fig. 2(c)] and two electron-like bands near M [Figs. 2(d) and 2(e)], which cross E_F . The band dispersions can be regarded as a superposition of the band structures of the FeAs and Ti₂As₂O layers. We assign the three hole-like bands near Γ [Figs. 2(a) and 2(b)] and the shallow electronlike bands near M [Fig. 2(d)] to the Fe 3d orbitals, while the hole-like band near X [Fig. 2(c)] and the deep electron-like band near M [Fig. 2(e)] are attributed to the Ti 3d orbitals.

The Fe-3d related band structure resembles those of other IB-SCs. In the IBSCs, there are generally two electron-like bands from Fe 3d near M. Only one electron-like band from Fe 3d is observed in our experiments [Fig. 2(d)], while another one from Fe 3d is not identified, most likely due to its extremely low spectral weight as it is folded from the adjacent M due to inequivalent As sites around Fe. The Ti-3d related band structure is similar to that of BaTi₂As₂O [23]. In BaTi₂As₂O, there are one electron-like band near Γ , one hole-like band near X and one electron-like band near M, which cross E_F . We do observe one electron-like band with a bottom of -0.5 eV at Γ [Fig. 2(b)] and our photon energy dependence measurements suggest it to originate mainly from Ti 3d states [Fig. S1 in the Supplement Materials], in agreement with the observation in $BaTi_2As_2O$ [23]. The spectral intensity of this band is smeared out as dispersing towards E_F , and its wave vector is estimated to be close to 0.4 π/a along ΓM by extrapolating the band dispersion to E_F .



FIG. 3. (Color online) (a) FS intensity plot of Ba22241 recorded at 150 K and hv = 55 eV with HP. The intensity is obtained by integrating the spectra within $\pm 10 \text{ meV}$ with respect to E_F . *a* represents the nearest neighbor Fe(Ti)-Fe(Ti) distance. (b) Same as (a) but taken with VP. (c) Extracted FSs of Ba22241. Red and blue symbols represent the extracted k_F points related to the FeAs and Ti₂As₂O layers, respectively. Solid and hollow symbols are extracted from the data taken at 150 and 30 K, respectively. Solid curves are guides for eyes. (d) FS intensity plot of Ba_{0.6}K_{0.4}Fe₂As₂ recorded with He $I\alpha$ resonance line (hv = 21.218 eV).

With the identification of the near- E_F bands, we extract the corresponding FSs and summarize them in Fig. 3(c). The extracted FSs related to the Fe 3*d* orbitals resemble those of other IBSCs, indicating that the FS topology of the FeAs layers is not changed by the intercalated Ti₂As₂O layers. One prominent feature of the Fe-related FSs is that the total enclosed area of the hole pockets near Γ is much larger than that of the electron pockets near M. Our k_z dependent measurements suggest that the electronic structure of Ba22241 is quasi-2D [Fig. S1 in the Supplement Materials]. By counting the Luttinger volume of 2D FS sheets and assuming a purely 2D FS, we obtain a hole doping of ~ 0.25 per Fe site. Indeed,

the Fe-related FSs look similar to those of the optimally-doped $Ba_{0.6}K_{0.4}Fe_2As_2$ with a hole doping of 0.2 per Fe site, as shown in Fig. 3(d). Note that the inner hole pockets are almost doubly-degenerate at $k_7 \sim 0$ for Ba_{0.6}K_{0.4}Fe₂As₂. By counting the volumes of the Ti-related FS sheets, we obtain an electron doping of ~ 0.25 per Ti site. Both the k_{τ} and temperature dependent ARPES results reflect bulk features [Figs. S1 and S2 in the Supplement Materials], thus excluding the possibility of charge polarization on the surface. Therefore, the most significant effect of the intercalation of metallic Ti₂As₂O layers is that the electrons are transferred from the FeAs layer to the Ti_2As_2O layer. The "washed out" nature of the Fe-3d bands is then a direct consequence of the interlayer charge transfer, since the effective hole-doping places this compound in the regime of strongly doping- and temperature-dependent coherence properties induced by Hund's rule coupling [10]. Analyzing further the many-body self-energies obtained within our DMFT calculations we find qualitatively similar incoherent behavior for the Fe-3d states in Ba22241 and optimally hole-doped BaFe₂As₂.

We analyze the electron transfer from Fe to Ti by comparing LDA and LDA + DMFT calculations for Ba22241 with experimental crystal structure, BaFe₂As₂, Ba_{0.63}K_{0.37}Fe₂As₂ and the compounds derived by splitting Ba22241 into BaTi₂As₂O and BaFe₂As₂ while keeping the same distance and angle between atoms within one layer. We construct localized Wannier-like orbitals within the same window [-8.16 eV, 8.16 eV] for all the compounds and extract the number of electrons, and the orbital-resolved electron counts for Fe-d and Ti-d, which are displayed on Table I. For Ba_{0.63}K_{0.37}Fe₂As₂ we have taken the band structure of BaFe₂As₂ with the experimental crystal structure of optimally doped BaFe₂As₂ and calculated the chemical potential such as to obtain the correct total number of electrons. The number of electrons in the different orbitals of Ba22241 obtained from LDA is independent of the particular stacking structure of this material, as we can see by comparing the calculation on Ba22241 to calculations on BaFe₂As₂ and BaTi₂As₂O crystals. Two effects are contributing to the global hole-doping of the Fe-d orbitals when going from BaFe₂As₂ to Ba22241. The effect of correlations in BaFe₂As₂ is to reduce the number of electrons in the correlated shell. If the Fe-As hybridization is weaker, electrons are more localized and this effect is enhanced. In Ba22241, the Fe-As distance is about 1% larger than in BaFe₂As₂, thus lowering the hybridization with As. The consequence can be seen by comparing the number of electrons in the Fe-d Wannier orbitals in BaFe₂As₂ in the structure of Ba22241 to BaFe₂As₂ in the experimental crystal structure: There is already a loss of 0.05 electrons per Fe in Ba22241. The second effect is a transfer of electrons from Fe to Ti due to correlations. In BaTi₂As₂O, correlations tend to increase the number of electrons in the Ti-d orbitals. This effect is enhanced when BaTi₂As₂O and BaFe₂As₂ are put together, leading to a transfer of about 0.1 electrons from Fe to Ti. That transfer happens notably (but not exclusively) through the Fe- d_{7^2} – Ti- d_{7^2} hybridization, as Ti and Fe are on top of each other. We stress

| ne structure ti | nan in Ba22 | 241 (2nd co | 1000000000000000000000000000000000000 | n the same structure that | 1 in Ba2224 | i (3rd column), BaF | e_2As_2 |
|-----------------|-------------------------------------|--------------------|--|---|-----------------------------------|-------------------------------------|-----------|
| timally doped | d BaFe ₂ As ₂ | (5th column | ı). | | | | |
| | Orbital | Ba22241 | BaFe ₂ As ₂ @Ba22241 | BaTi ₂ As ₂ O@Ba22241 | BaFe ₂ As ₂ | $\boxed{Ba_{0.63}K_{0.37}Fe_2As_2}$ | |
| | Fe d_{z^2} | 1.30 (1.41) | 1.33 (1.42) | | 1.35 (1.43) | 1.30 (1.43) | |
| | Fe $d_{x^2-y^2}$ | 1.33 (1.23) | 1.34 (1.23) | | 1.32 (1.25) | 1.32 (1.25) | |
| | Fe d_{xy} | 1.20 (1.40) | 1.23 (1.40) | | 1.26 (1.40) | 1.20 (1.33) | |
| | Fe $d_{xz} + d_{yz}$ | 1.27 (1.35) | 1.30 (1.34) | | 1.32 (1.34) | 1.27 (1.29) | |
| | Total Fe d | 6.38 (6.76) | 6.50 (6.75) | | 6.56 (6.77) | 6.36 (6.61) | |
| | Ti d_{z^2} | 0.46 (0.43) | | 0.41 (0.42) | | | |
| | Ti $d_{x^2-y^2}$ | 0.39 (0.39) | | 0.38 (0.38) | | | |
| | Ti d_{xy} | 0.63 (0.69) | | 0.60 (0.69) | | | |
| | Ti d_{xz} | 0.36 (0.15) | | 0.33 (0.15) | | | |

0.48 (0.45)

2.20 (2.09)

TABLE I. Orbital-resolved electron count in Wannier functions calculated by LDA+DMFT (LDA) for Ba22241 (1st column), $BaFe_2As_2$ with the same structure than in Ba22241 (2nd column), $BaTi_2As_2O$ with the same structure than in Ba22241 (3rd column), $BaFe_2As_2$ (4th column) and optimally doped $BaFe_2As_2$ (5th column).

that the band with bottom around -0.5 eV at the Γ point is of mixed Ti d_{z^2} and Fe d_{z^2} characters, and wrongly predicted by LDA while correctly captured by our two-correlated shells LDA + DMFT.

Total Ti d 2.29 (2.09)

0.45 (0.45)

Ti d_v

In conclusion, we studied the electronic structure of Ba22241 and revealed a large charge transfer between the FeAs and intercalated Ti₂As₂O layers, which is identified as a consequence of electronic correlations in the 3*d* shells by the LDA + DMFT calculations. This provides an alternative route of effective doping without element substitution for the IBSCs and thus without introducing disorder. Furthermore, our results prove the presence of strong interlayer coupling in Ba22241 arising from the Fe- d_{z^2} – Ti- d_{z^2} hybridization and the metallic nature of the intercalated Ti₂As₂O layer. It has been argued that, as in the high- T_c cuprate superconductors, the FeAs interlayer coupling can play a crucial role in enhancing T_c in the IBSCs [24]. Further studies for the IBSCs with metallic intercalated layers may be a fruitful path for reaching higher T_c in the IBSC family.

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Correlation-induced self-doping in intercalated iron-pnictide superconductor Ba₂Ti₂Fe₂As₄O -Supplementary material

As seen in Fig. S1 (a)-(c), the Fermi surface near the Brillouin zone centre exhibits an obvious warping with a period of $2\pi/c'$, suggesting that the ARPES data reflect the bulk electronic structure. This Fermi surface is assigned to the hole-like Fe $3d_{xz}$ band. This indicates that the interlayer coupling between the adjacent FeAs layers is not negligible, which can be attributed to the metallic nature of the intercalated BaTi₂As₂O layer.

In Fig. S1 (d), the spectrum at the Brillouin zone centre has two structures, which correspond to the shallow flat band and the bottom of the deep band, respectively, in Fig.S1 (e) and (f). The spectral intensities of the shallow and deep ones are strongly suppressed at hv = 53 and 34 eV, respectively, corresponding to the Fe 3p-3d and Ti 3p-3d antiresonances, respectively [S1].



FIG. S1. (a) ARPES intensity plot in the $k_y \cdot k_z$ plane recorded at 25 K with different photon energies from 35 to 60 eV with horizontal polarization. The intensity is obtained by integrating the spectra within ±10 meV with respect to E_F . An inner potential of 14 eV is used to obtain k_z . c' = c/2, where c represents the lattice parameter perpendicular to the FeAs plane. (b) Curvature intensity plot of the ARPES intensity in panel (a). (c) Corresponding momentum distribution curves (MDCs) at E_F with different k_z . (d) Valence band spectra at the Brillouin zone center recorded with different photon energies from 26 to 62 eV. (e) and (f) ARPES intensity plots at $k_x =$ 0 recorded with 34 and 53 eV photons, respectively.

The band dispersion around M derived from Ti 3*d* exhibits a dramatic change around 120 K, which is consistent with the anomaly in resistivity and magnetic susceptibility of Ba₂Ti₂Fe₂As₄O [S2]. Since both the k_z and temperature dependent ARPES results reflect bulk features, the possibility of charge polarization on the surface can be excluded.



FIG. S2. (a) Two-dimension curvature intensity plots of the cuts at M ($k_x = \pi/a$) at various temperatures between 30 and 150 K. (b) and (c) Corresponding energy distribution curves (EDCs) at 30 and 150 K, respectively. (d) Band dispersions taken from EDCs and MDCs at 30 and 150 K. (e) Binding energy of the top of the hump as a function of temperature.



FIG. S3. (a)-(d) Contributions of the Fe 3d, Ti 3d, As1 4p in the FeAs layers, and As2 4p in the Ti₂As₂O layers to the LDA calculated band structure of Ba₂Ti₂Fe₂As₄O, respectively. The contribution is represented by both the symbol size and the color scale.

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